

L Number	Hits	Search Text	DB	Time stamp
1	27375	semiconductor and (tft or (thin adj film adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/02 09:51
2	343	(semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or ((aluminum adj nitride) and oxygen))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/02 09:53
3	343	((semiconductor and (tft or (thin adj film adj transistor))) and (alno or alon or ((aluminum adj nitride) and oxygen))) and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/02 10:41
4	237	(semiconductor and (tft or (thin adj film adj transistor))) and (alnc or alcn or ((aluminum adj nitride) and carbon))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/02 10:42